

LC²MOS High Speed, Quad SPST Switch

ADG201HS

FEATURES

50ns max Switching Time Over Full Temperature Range
Low R_{ON} (30Ω typ)
Single Supply Specifications for +10.8V to +16.5V Operation
Extended Plastic Temperature Range (-40°C to +85°C)
Break-Before-Make Switching
Low Leakage (100pA typ)
44V Supply max Rating
Available in 16-Lead DIP/SOIC and 20-Lead LCCC/PLCC Packages

ADG201HS (K, B, T) Replaces HI-201HS ADG201HS (J, A, S) Replaces DG271

GENERAL DESCRIPTION

The ADG201HS is a monolithic CMOS device comprising four independently selectable SPST switches. It is designed on an enhanced LC^2MOS process which gives very fast switching speeds and low R_{ON} .

The switches also feature break-before-make switching action for use in multiplexer applications and low charge injection for minimum transients on the output when switching the digital inputs.

ORDERING GUIDE

Model ¹	Temperature Range	Package Option ²
ADG201HSJN	-40° C to $+85^{\circ}$ C	N-16
ADG201HSKN	-40°C to $+85^{\circ}\text{C}$	N-16
ADG201HSKR	-40°C to $+85^{\circ}\text{C}$	R-16
ADG201HSAQ	-40°C to $+85^{\circ}\text{C}$	Q-16
ADG201HSBQ	-40°C to $+85^{\circ}\text{C}$	Q-16
ADG201HSJP	-40°C to $+85^{\circ}\text{C}$	P-20A
ADG201HSKP	-40°C to $+85^{\circ}\text{C}$	P-20A
ADG201HSSQ	-55°C to +125°C	Q-16
ADG201HSTQ ³	−55°C to +125°C	Q-16
ADG201HSTE ³	$-55^{\circ}\text{C to} + 125^{\circ}\text{C}$	E-20A

NOTES

¹To order MIL-STD-883, Class B processed parts, add /883B to T grade part numbers. See the Analog Devices Military Products Databook (1994) for military data sheet. ²E = Leadless Ceramic Chip Carrier; N = Narrow Plastic DIP; P = Plastic Leaded Chip Carrier; Q = Cerdip; R = 0.15" Small Outline IC (SOIC). ³Standard Military Drawing (SMD) approved by DESC.

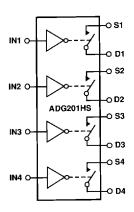
SMD numbers are

5962-86716012X (ADG201HSTE/883B) 5962-8671601EX (ADG201HSTQ/883B)

REV. B

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FUNCTIONAL BLOCK DIAGRAM



PRODUCT HIGHLIGHTS

1. 50ns max t_{ON} and t_{OFF}:

The ADG201HS top grades (K, B, T) have guaranteed 50ns max turn-on and turn-off times over the full operating temperature range. The lower grades (J,A,S) have guaranteed 75ns switching times over the full operating temperature range.

2. Single Supply Specifications:

The ADG201HS is fully specified for applications which require a single positive power supply in the +10.8V to +16.5V range.

3. Low Leakage:

Leakage currents in the range of 100pA make these switches suitable for high precision circuits. The added feature of break-before-make allows for multiple outputs to be tied together for multiplexer applications while keeping leakage errors to a minimum.

IN	Switch Condition		
0	ON		
1	OFF		

Truth Table

ADG201HS* Product Page Quick Links

Last Content Update: 08/30/2016

Comparable Parts

View a parametric search of comparable parts

Documentation <a>□

Application Notes

• AN-355: Behind the Switch Symbol

Data Sheet

 ADG201HS: LC²MOS High Speed, Quad SPST Switches Data Sheet

Reference Materials

Analog Dialogue

• Choosing High-Speed Signal Processing Components for Ultrasound Systems

Product Selection Guide

• Switches and Multiplexers Product Selection Guide

Technical Articles

- CMOS Switches Offer High Performance in Low Power, Wideband Applications
- · Data-acquisition system uses fault protection
- Enhanced Multiplexing for MEMS Optical Cross Connects
- Temperature monitor measures three thermal zones

Design Resources -

- ADG201HS Material Declaration
- · PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

Discussions <a>□

View all ADG201HS EngineerZone Discussions

Sample and Buy -

Visit the product page to see pricing options

Technical Support -

Submit a technical question or find your regional support number

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ADG201HS — SPECIFICATIONS

DUAL SUPPLY ($V_{DD}=+13.5V$ to +16.5V, =-13.5V to -16.5V, GND =0V, $V_{IN}=-100$ (Logic High Level) or 0.8 V (Logic Low Level) unless otherwise noted)

Parameter	Version	+25°C	$T_{min} - T_{max}^{1}$	Units	Comments
ANALOG SWITCH					
Analog Signal Range	All	V_{SS}	V_{SS}	Vmin	
	All	V_{DD}	V_{DD}	V max	
R _{ON}	All	30	_	Ω typ	$-10V \le V_S \le +10V$, $I_{DS} = 1mA$; Test Circuit 1
NON	All	50	75	Ωmax	201 113 1 201
R _{ON} Drift	All	0.5	_	%/°C typ	$-10V \le V_S \le +10V, I_{DS} = 1mA$
R _{ON} Match	All	3	_	% typ	$-10V \leqslant V_{S} \leqslant +10V, I_{DS} = 1mA$
					_
I _S (OFF), Off Input Leakage ²	All	0.1	20	nA typ	$V_D = \pm 14V$; $V_S = \mp 14V$; Test Circuit 2
	J, K, A, B	1	20	nA max	
	S, T	1	60	nA max	N . 14V V14V TCiris 2
I _D (OFF), Off Output Leakage ²	All	0.1	••	nA typ	$V_D = \pm 14V$; $V_S = \mp 14V$; Test Circuit 2
	J, K, A, B	1	20	nA max	
	S,T	1	60	nA max	37 37 - 1 1437. Teet Oinit 2
I _D (ON), On Channel Leakage ²	All	0.1		nA typ	$V_D = V_S = \pm 14V$; Test Circuit 3
	J, K, A, B	1	20	nA max	
	S,T	1	60	nA max	
DIGITAL CONTROL					
V _{INH} , Input High Voltage	All	2.4	2.4	V min	
V _{INL} , Input Low Voltage	All	0.8	0.8	V max	
I _{INL} or I _{INH}	All	1	1	μA max	
C _{IN}	All	8	8	pF max	
DYNAMIC CHARACTERISTICS	100	-	•		
t _{on}	K, B, T	50	50	ns max	Test Circuit 4
ON	J, A, S	75	75	ns max	
t _{OFF1}	K, B, T	50	50	ns max	Test Circuit 4
OFFI	J,A,S	75	75	ns max	
t _{OFF2}	All	150	_	ns typ	Test Circuit 4
topen	Ali	5	5	ns typ	t _{ON} -t _{OFF1} ; Test Circuit 4
Output Settling Time to 0.1%	All	180	_	ns typ	$V_{IN} = 3V \text{ to } 0V$; Test Circuit 4
OFF Isolation	All	72	_	dB typ	$V_S = 3V \text{ rms}, f = 100kHz, R_L = 1k\Omega;$
					$C_L = 10pF$; Test Circuit 5
Channel-to-Channel Crosstalk	All	86	_	dB typ	$V_S = 3V \text{ rms}, f = 100kHz, R_L = 1k\Omega;$
CIMILE TO CIMILED OF COOKING					$C_L = 10 pF$; Test Circuit 6
Q _{INI} , Charge Injection	All	10	_	pC typ	$R_S = 0\Omega$, $V_S = 0V$; Test Circuit 7
C _S (OFF)	All	10	_	pF typ	
C _D (OFF)	All	10	_	pF typ	
$C_D, C_S(ON)$	All	30	_	pF typ	
C _{DS} (OFF)	All	0.5	_	pF typ	
POWER SUPPLY					<u> </u>
I _{DD}	All	10	10	mA max	
I _{SS}	All	6	6	mA max	
					$V_{DD} = +15V, V_{SS} = -15V$
Power Dissipation	Ali	240	240	mW max	VDD - T13V, VSS13V

NOTES

Temperature ranges are as follows: ADG201HSJ, K; -40°C to +85°C

ADG201HSA, B; -40°C to +85°C

ADG201HSS, T; -55°C to +125°C

 $^{^2}Leakage \ specifications \ apply \ with \ a\ V_D \quad (V_S) \ of \ \pm \ 14V \ or \ with \ a\ V_D (V_S) \ of \ 0.5V \ within \ the \ supply \ voltages \ (V_{DD},V_{SS}), \ whichever \ is \ the \ minimum.$

Specifications subject to change without notice.

 $\textbf{SINGLE SUPPLY} \ \ (\textbf{V}_{DD} = +\ 10.8 \textbf{V to}\ +\ 16.5 \textbf{V}, \ \textbf{V}_{SS} = \textbf{GND} = \textbf{OV}, \ \textbf{V}_{IN} = \textbf{3V} \ \, [\textbf{Logic High Level}] \ \, \text{or } \textbf{0.8V} \ \, [\textbf{Logic Low Level}] \ \, \text{unless otherwise noted})$

Parameter	Version	+ 25°C	$T_{min} - T_{max}$	Units	Comments
ANALOG SWITCH					
Analog Signal Range	All	V_{SS}	V_{SS}	Vmin	
	All	V_{DD}	V_{DD}	V max	
R _{ON}	All	65	_	Ω typ	$0V \le V_S \le +10V$, $I_{DS} = 1mA$; Test Circuit 1
···	All	90	120	Ω max	
R _{ON} Drift	All	0.5	_	%/°C typ	$0V \leq V_S \leq +10V$, $I_{DS} = 1mA$
R _{ON} Match	All	3	_	% typ	$0V \leq V_S \leq +10V$, $I_{DS} = 1mA$
I _S (OFF), Off Input Leakage ¹	All	0.1		nA typ	$V_D = +10V/+0.5V$; $V_S = +0.5V/+10V$; Test Circuit 2
	J, K, A, B	1	20	пA max	
	S, T	1	60	nA max	
ID (OFF), Off Output Leakage ¹	All	0.1		nA typ	$V_D = +10V/+0.5V$; $V_S = +0.5V/+10V$; Test Circuit 2
	J, K, A, B	1	20	nA max	
	S, T	1	60	nA max	
I _D (ON), On Channel Leakage ¹	All	0.1		nA typ	$V_D = V_S = +10V/+0.5V$; Test Circuit 3
	J, K, A, B	1	20	nA max	
	S, T	1	60	nA max	
DIGITAL CONTROL					
V _{INH} , Input High Voltage	All	2.4	2.4	V min	
V _{INL} , Input Low Voltage	All	0.8	0.8	V max	
I _{INL} or I _{INH}	All	1	1	μA max	
C _{IN}	All	8	8	pF max	
DYNAMIC CHARACTERISTICS			-		
t _{ON}	K, B, T	50	70	ns max	Test Circuit 4
	J, A, S	75	90	ns max	
t _{OFF1}	K, B, T	50	70	ns max	Test Circuit 4
•••	J, A, S	75	90	ns max	
t _{OFF2}	All	150	_	ns typ	Test Circuit 4
topen	All	5	5	ns typ	t _{ON} -t _{OFF1} ; Test Circuit 4
Output Settling Time to 0.1%	All	180	_	ns typ	$V_{IN} = 3V \text{ to } 0V$; Test Circuit 4
OFF Isolation	All	72	_	dB typ	$V_S = 3V \text{ rms}, f = 100kHz, R_L = 1k\Omega;$
					$C_L = 10pF$; Test Circuit 5
Channel-to-Channel Crosstalk	All	86	_	d B typ	$V_S = 3V \text{ rms}, f = 100kHz, R_L = 1k\Omega;$
					$C_L = 10pF$; Test Circuit 6
Q _{INJ} , Charge Injection	All	10	-	pC typ	$R_S = 0\Omega$, $V_S = 0V$; Test Circuit 7
$C_S(OFF)$	All	10	_	pF typ	
$C_{D}(OFF)$	A 11	10	_	pF typ	
$C_D, C_S(ON)$	All	30	_	pF typ	
C _{DS} (OFF)	All	0.5		pF typ	
POWER SUPPLY					
$I_{ m DD}$	All	10	10	mA max	
Power Dissipation	All	150	150	mW max	$V_{DD} = +15V$

NOTE ${}^{l} The \ leakage \ specifications \ degrade \ marginally \ (typically \ lnA \ at \ 25^{\circ}C) \ with \ V_D(V_S) = V_{SS}.$

Specifications subject to change without notice.

ADG201HS

ABSOLUTE MAXIMUM RATINGS*	Power Dissipation (Any Package)
$(T_{\Lambda} = 25^{\circ}\text{C unless otherwise noted})$	Up to $+75^{\circ}$ C 470mW
	Derates above $+75^{\circ}$ C by 6mW/°C
V_{DD} to V_{SS}	Operating Temperature
V_{DD} to GND	Commercial (J, K Version) -40° C to $+85^{\circ}$ C
V_{SS} to GND^1	Industrial (A, B Version) $\dots \dots -40^{\circ}$ C to $+85^{\circ}$ C
Analog Inputs ²	Extended (S, T Version) $\dots \dots -55^{\circ}$ C to $+125^{\circ}$ C
Voltage at S, D $\dots \dots $	Storage Temperature Range65°C to +150°C
$V_{DD} + 2V or$	Lead Temperature (Soldering 10sec) + 300°C
20mA, Whichever Occurs First	
Continuous Current, S or D 20mA	NOTES
Pulsed Current S or D	¹ If V_{SS} is open circuited with V_{DD} and GND applied, the V_{SS} pin will be pulled positive, exceeding the Absolute Maximum Ratings. If this possibility exists,
1ms Duration, 10% Duty Cycle 70mA	a Schottky diode from V_{SS} to GND (cathode end to GND) ensures that the
Digital Inputs ²	Absolute Maximum Ratings will be observed.
Voltage at IN V_{SS} -4V to	² Overvoltage at IN, S or D, will be clamped by diodes. Current
$V_{\mathrm{DD}} + 4 \mathrm{V} \mathrm{or}$	should be limited to the maximum rating above.
20mA, Whichever Occurs First	

^{*}COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION:

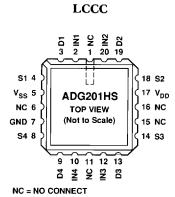
ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are inserted.

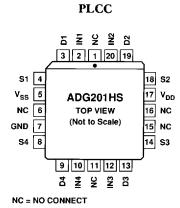


PIN CONFIGURATIONS

IN1 16 IN2 D1 2 15 D2 S1 S2 ADG201HS 13 V_{DD} v_{ss} TOP VIEW GND 5 12 NC (Not to Scale) 6 S3 **S4** 7 10 D3 D4 8 IN4 9 IN3 NC = NO CONNECT

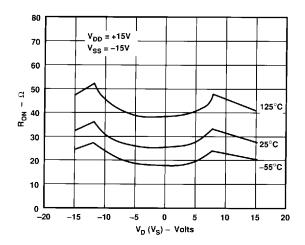
DIP, SOIC



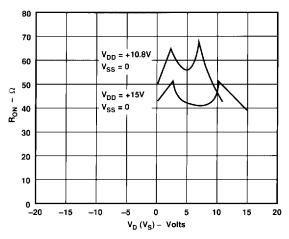


Typical Performance Characteristics—ADG201HS

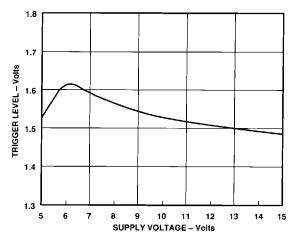
The switches are guaranteed functional with reduced single or dual supplies down to 4.5V.



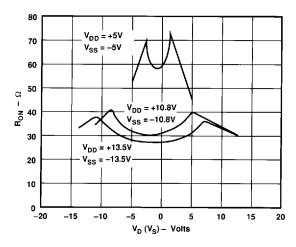
 R_{ON} as a Function of V_D (V_S): Dual Supply Voltage



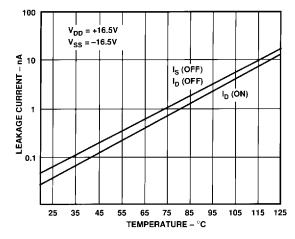
 R_{ON} as a Function of V_D (V_S): Single Supply Voltage, $T_A = +25^{\circ}C$



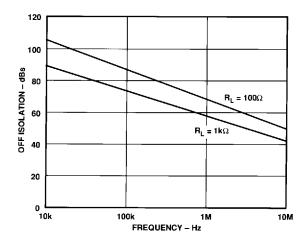
Trigger Levels vs. Power Supply Voltage, Dual or Single Supply, $T_A = +25^{\circ}C$



 R_{ON} as a Function of V_D (V_S): Dual Supply Voltage, $T_A = +25^{\circ}C$

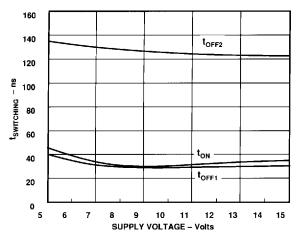


Leakage Current as a Function of Temperature Dual Supply Voltage. (Note: Leakage Currents Reduce as the Supply Voltages Reduce)

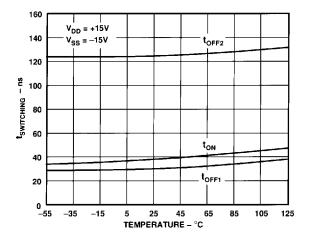


Off Isolation vs. Signal Frequency; Dual or Single 15V Supplies, $T_A = +25^{\circ}C$

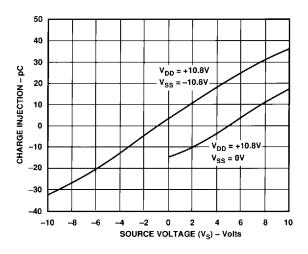
ADG201HS—Typical Performance Characteristics (Continued)



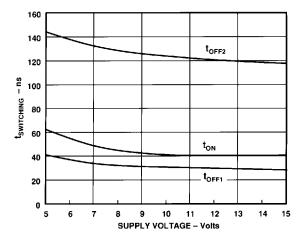
Switching Time vs. Supply Voltage (Dual Supply): $T_A = +25$ °C. (Note: See Test Circuit 4. For $V_{DD} < 10V$, $V_S = V_{DD}$)



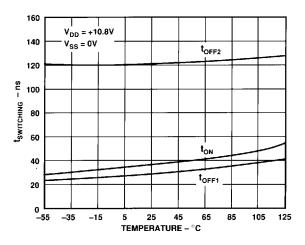
Switching Time vs. Temperature: Dual Supply Voltage



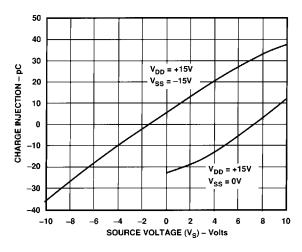
Charge Injection vs. Source Voltage (V_S) for Dual and Single 10.8V Supplies: $T_A = +25^{\circ}C$



Switching Time vs. Supply Voltage (Single Supply): $T_A - +25^{\circ}C$. (Note: See Test Circuit 4. For $V_{DD} < 10V$, $V_S = V_{DD}$)



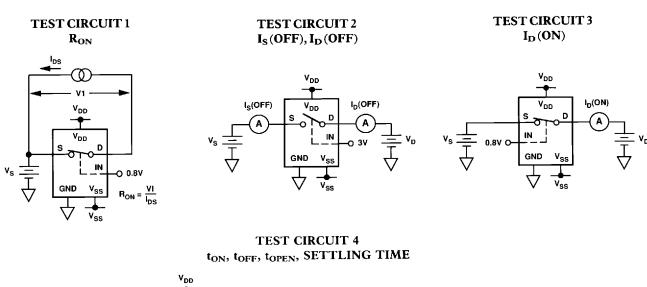
Switching Time vs. Temperature: Single Supply Voltage

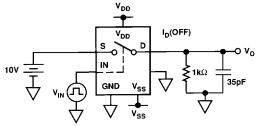


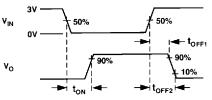
Charge Injection vs. Source Voltage (V_S) for Dual and Single 15V Supplies: $T_A = +25^{\circ}C$

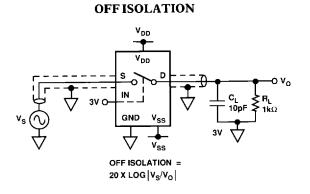
Test Circuits—ADG201HS

Note: All digital input signal rise and fall times measured from 10% to 90% of 3V. $t_R=t_F=5 ns$. Decoupling capacitors (0.01 μF min) from $V_{\rm DD}$ and $V_{\rm SS}$ to GND are recommended to achieve specified performance.

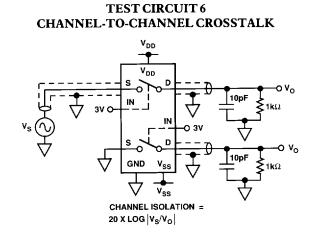




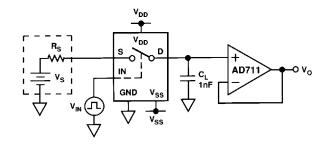


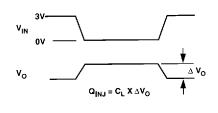


TEST CIRCUIT 5



TEST CIRCUIT 7 CHARGE INJECTION

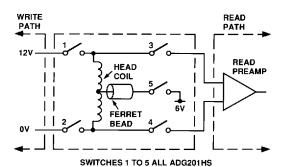




ADG201HS

SINGLE SUPPLY DISK DRIVE APPLICATION

The excellent performance of the ADG201HS with single supply operation makes it suitable in applications such as disk drives where only positive power supply voltages are normally available. The accompanying circuit shows a typical application for the ADG201HS in the read/write head switching section of a disk drive. The circuit allows data (0s and 1s) to be written to and read from a disk. The principal advantage offered by the ADG201HS is that it retains very fast switching speed with single supply operation (see Single Supply Specifications). This allows disk drives to run at higher data rates.



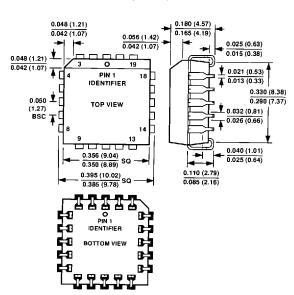
SWITCH STATES/FUNCTION				
SWITCH	WR			
NUMBER	"0"	"1"	READ	
1	OFF	ON	OFF	
2	ON	OFF	OFF	
3	OFF	OFF	ON	
4	OFF	OFF	ON	
5	ON	ON	OFF	

ADG201HS in the Read/Write Head Switching Circuit of a Disk Drive

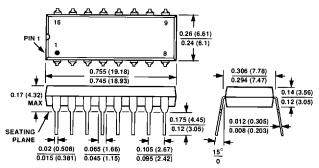
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

20-Terminal Plastic Leaded Chip Carrier (P-20A)

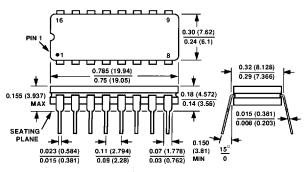


16-Pin Plastic DIP (N-16)



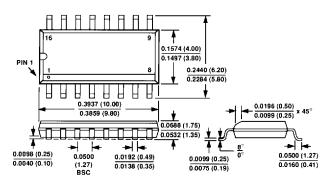
LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH LEADS ARE SOLDER OR TIN-PLATED KOVAR OR ALLOY 42

16-Pin Cerdip (Q-16)



LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH
LEADS ARE SOLDER OR TIN-PLATED KOVAR OR ALLOY 42

16-Lead Narrow Body SOIC (R-16A)



20-Terminal Leadless Ceramic Chip Carrier (E-20A)

